

### PNP -1.0A -80V Middle Power Transistor

Parameter	Value
$V_{\sf CEO}$	-80V
I <sub>C</sub>	-1.0A

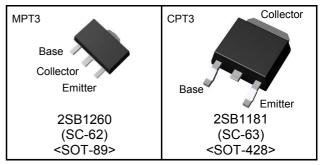
#### Features

- 1) Suitable for Middle Power Driver
- 2) Complementary NPN Types: 2SD1898 / 2SD1733
- 3) Low V<sub>CE(sat)</sub>

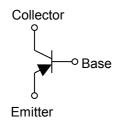
$$V_{CE(sat)} = -0.4V \text{ Max. } (I_C/I_B = -500\text{mA/} -50\text{mA})$$

4) Lead Free/RoHS Compliant.

#### Outline



#### •Inner circuit



### Applications

Motor driver , LED driver Power supply

### Packaging specifications

Part No.	Package	Package size (mm)	Taping code	Reel size (mm)	Tape width (mm)	Basic ordering unit (pcs)	Marking
2SB1260	MPT3	4540	T100	180	12	1,000	BE
2SB1181	CPT3	6595	TL	330	16	2,500	B1181

### ● **Absolute maximum ratings** (Ta = 25°C)

Parameter		Symbol	Values	Unit	
Collector-base voltage		$V_{CBO}$	-80	V	
Collector-emitter voltage		V <sub>CEO</sub>	-80	V	
Emitter-base voltage		V <sub>EBO</sub>	<b>-5</b>	V	
Collector current	DC	I <sub>C</sub>	-1.0	А	
Collector current	Pulsed	I <sub>CP</sub> *1	-2.0	Α	
	2SB1260		0.5 <sup>*2</sup>	w	
Power dissipation	2361200	$ P_D$	2.0 *3		
rowei dissipation	2SB1181	' D	1 *4	W	
	2361101		10 <sup>*5</sup>	¬	
Junction temperature		T <sub>j</sub>	150	°C	
Range of storage temperature		$T_{stg}$	−55 to +150	°C	

<sup>\*1</sup> Pw=20ms, duty=1/2

### ●Electrical characteristics (Ta = 25°C)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Collector-emitter breakdown voltage	BV <sub>CEO</sub>	I <sub>C</sub> = -1mA	-80	-	-	V
Collector-base breakdown voltage	BV <sub>CBO</sub>	$I_{C} = -50 \mu A$	-80	-	-	V
Emitter-base breakdown voltage	BV <sub>EBO</sub>	$I_{E} = -50 \mu A$	-5	-	-	V
Collector cut-off current	I <sub>CBO</sub>	V <sub>CB</sub> = -60V	-	-	-1	μА
Emitter cut-off current	I <sub>EBO</sub>	V <sub>EB</sub> = -4V	-	-	-1	μА
Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	$I_C = -1A, I_B = -50mA$	-	-	-0.4	V
DC current gain	h <sub>FE</sub>	$V_{CE} = -3V, I_{C} = -0.1A$	120	-	390	-
Transition frequency	f <sub>⊤</sub>	$V_{CE} = -10V, I_{E} = 50mA$ f=100MH <sub>Z</sub>	-	100	-	MHz
Output capacitance	C <sub>ob</sub>	$V_{CB} = -10V, I_{E} = 0A$	-	20 *6	ı	pF
	Oob	f = 1MHz	-	25 <sup>*7</sup>	-	pF

<sup>\*6 2</sup>SB1260

## ●h<sub>FE</sub> rank categories

Rank	Q	R
h <sub>FE</sub>	120 to 270	180 to 390

<sup>\*2</sup> Each terminal mounted on a reference land

<sup>\*3</sup> Mounted on a ceramic board (40×40×0.7 mm)

<sup>\*4</sup> Mounted on a substrate

<sup>\*5</sup> T<sub>C</sub>=25°C

<sup>\*7 2</sup>SB1181

### ●Electrical characteristic curves(Ta = 25°C)

Fig.1 Ground Emitter Propagation Characteristics

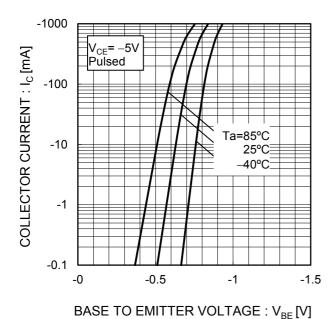
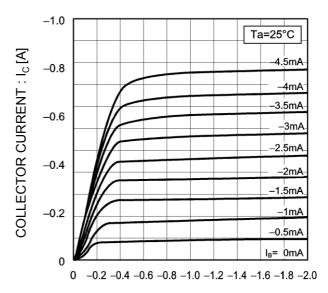


Fig.2 Typical Output Characteristics



COLECTOR TO EMITTE VOLTAGE :  $V_{CE}[V]$ 

Fig.3 DC Current Gain vs. Collector Current(I)

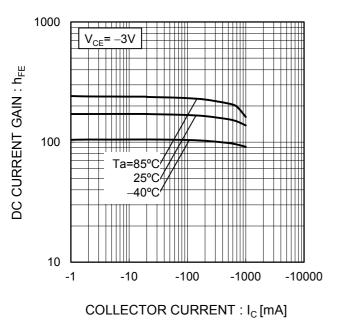
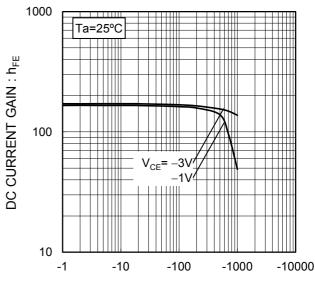
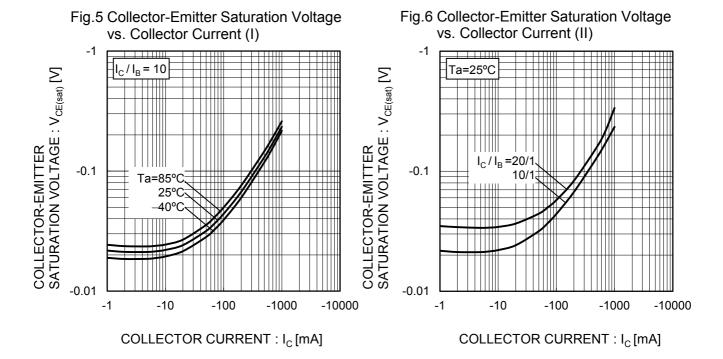
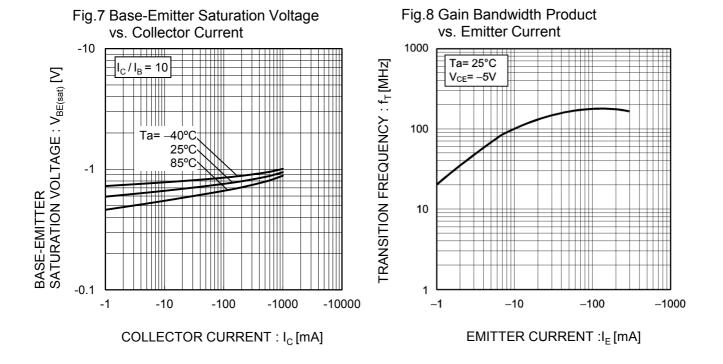


Fig.4 DC Current Gain vs. Collector Current(II)



### ●Electrical characteristic curves(Ta = 25°C)





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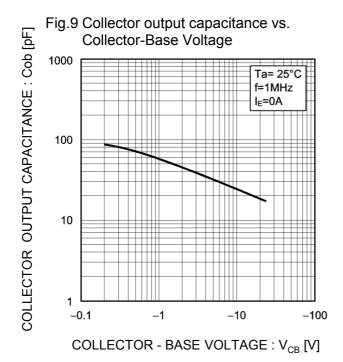
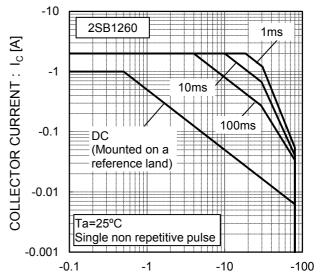
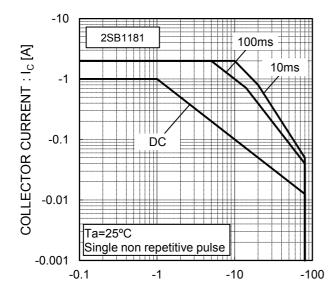


Fig.10 Safe Operating Area



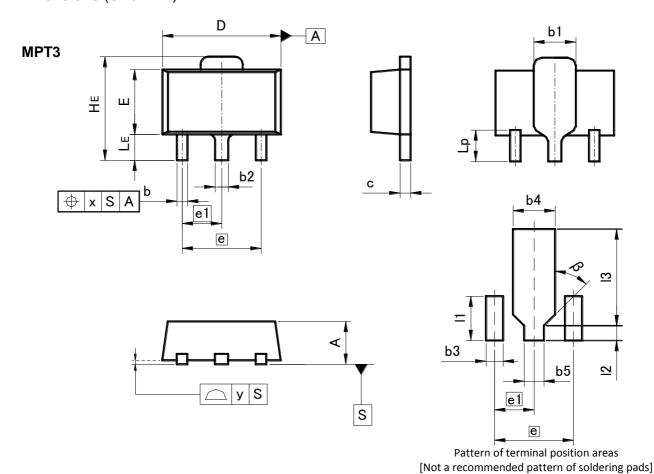
COLLECTOR TO EMITTER VOLTAGE: V<sub>CE</sub> [V]

Fig.11 Safe Operating Area



COLLECTOR TO EMITTER VOLTAGE :  $V_{CE}[V]$ 

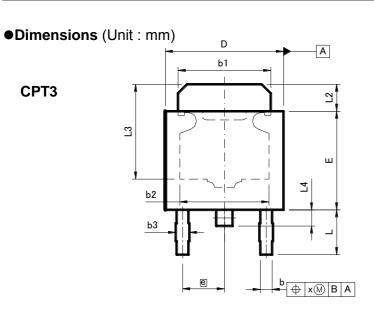
## ●Dimensions (Unit: mm)

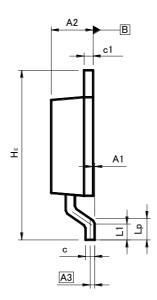


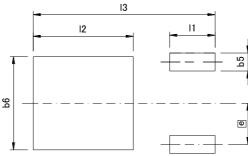
DIM	MILIM	MILIMETERS		HES
DIM	MIN	MAX	MIN	MAX
Α	1.40	1.50	0.055	0.059
b	0.30	0.50	0.012	0.020
b1	1.50	1.70	0.059	0.067
b2	0.40	0.60	0.016	0.024
С	0.35	0.50	0.014	0.020
D	4.40	4.70	0.173	0.185
Е	2.40	2.70	0.094	0.106
е	3.0	00	0.1	18
e1	1.	50	0.059	
HE	3.70	4.30	0.146	0.169
LE	0.80	1.20	0.031	0.047
Lp	1.01	1.41	0.040	0.056
X	_	0.15	-	0.006
У	_	0.10	ı	0.004

DIM	MILIMI	MILIMETERS		HES
	MIN	MAX	MIN	MAX
b3	I	0.65	1	0.026
b4	-	1.70	_	0.067
b5	ı	0.75	ı	0.030
1	ı	1.71	1	0.067
12	ı	0.58	1	0.023
13	-	3.72	-	0.146
β	45°		45	0

Dimension in mm / inches







Pattern of terminal position areas [Not a recommended pattern of soldering pads]

DIM	MILIM	ETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
A1	0.00	0.15	0.000	0.006
A2	2.20	2.50	0.087	0.098
A3	0.:	25	0.0	10
b	0.55	0.75	0.022	0.030
b1	5.00	5.30	0.197	0.209
b2	5.0	00	0.1	97
b3	0.	75	0.0	30
С	0.40	0.60	0.016	0.024
c1	0.40	0.60	0.016	0.024
D	6.30	6.70	0.248	0.264
Е	5.40	5.80	0.213	0.228
е	2.3	30	0.091	
HE	9.00	10.00	0.354	0.394
L	2.20	2.80	0.087	0.110
L1	0.80	1.40	0.031	0.055
L2	1.20	1.80	0.047	0.071
L3	5.30		0.209	
L4	0.90		0.035	
Lp	1.00	1.60	0.039	0.063
Х	_	0.25	_	0.010

DIM	MILIMI	IETERS IN		ICHES	
DIM	MIN	MAX	MIN	MAX	
b5	ı	1.00	ı	0.04	
b6	1	5.20	ı	0.205	
l1	-	2.50	-	0.098	
12	_	5.50	_	0.217	
13	-	10.00	_	0.394	

Dimension in mm / inches

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